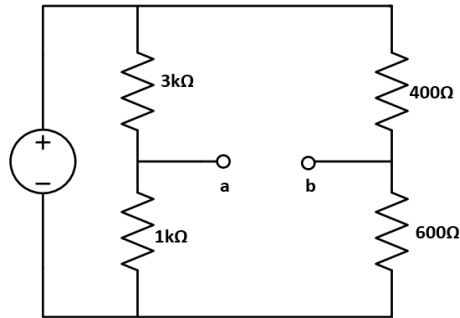


SOLUTIONS

Solution of pre-tutorial:

Thevenin equivalent across a-b are to be estimated.



Notice that $3\text{ k}\Omega$ and $1\text{ k}\Omega$ resistors are in parallel and so are the $400\text{ }\Omega$ and $600\text{ }\Omega$ resistors. The two parallel combinations form a series combination with respect to terminals **a** and **b**.

Hence, $R_{th} = 3000 || 1000 + 400 || 600 = 990\text{ }\Omega$

Next, using the voltage division principle

$$V_a = \frac{1000}{1000 + 3000} \times 220 = 55\text{ V}$$

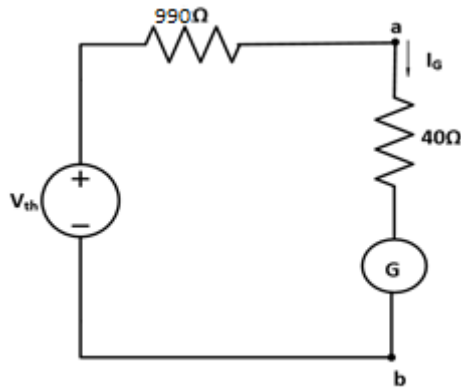
$$V_b = \frac{600}{600 + 400} \times 220 = 132\text{ V}$$

Applying KVL around loop **ab** gives

$$-V_a + V_{th} + V_b = 0$$

$$\Rightarrow V_{th} = V_a - V_b = 55 - 132 = -77\text{ V}$$

The equivalent circuit is:

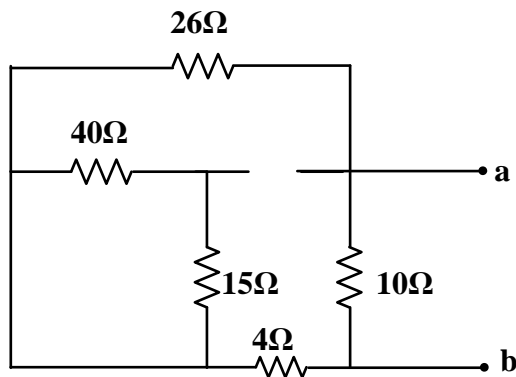


$$I_G = \frac{V_{Th}}{R_{Th} + R_m} = \frac{-77}{990 + 40} = -74.76 \text{ mA}$$

The negative sign indicates that the current flows in the direction opposite to the one assumed, that is, from terminal **b** to terminal **a**.

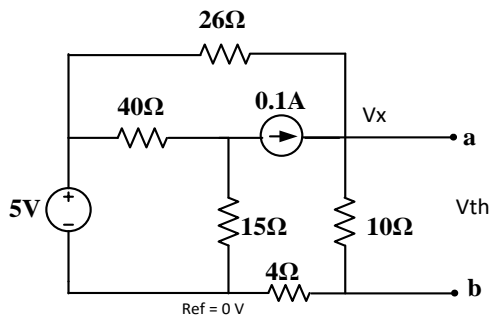
Solution of problem 2:

Method-1

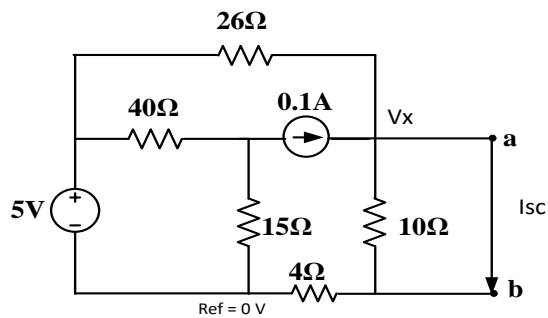


Deactivating the independent sources to ZERO, both the resistors 26 Ω and 4 Ω get connected in series giving a total of 30 Ω. Further, this total 30 Ω appears in parallel with the 10 Ω between the terminals a-b. Thus, the Norton's equivalent resistance becomes $30 \parallel 10 = 7.5 \Omega$.

Method -2 ($R_{th} = V_{th} / I_{sc}$)



(Fig. 1 for finding V_{th})



(Fig. 2 for finding I_{sc})

Open circuit voltage V_{th} and short-circuit current I_{sc} in a-b are estimated:

From Fig. 1, $(V_x - 5)/26 + V_x/14 = 0.1 \Rightarrow V_{th} = (10/14) V_x = 1.9 \text{ V}$

From Fig. 2, $(V_x - 5)/26 + V_x/4 = 0.1 \Rightarrow V_x = 1.013$ and therefore, $I_{sc} = V_x/4 = 0.253 \text{ A}$

Then, $R_{eq} = V_{th} / I_{sc} = 1.9/0.253 = 7.510$ (approx.)

Equivalent resistance obtained by open-circuit voltage/ short-circuit current method should yield the same 7.5Ω and differences, if any, are due to rounding errors only.

Solution of problem 3:

After disconnecting R_L , let the voltage across $0.5 \text{ k}\Omega$ be V_x and the open circuit voltage across **a-b** be the Thevenin's voltage V_{th} .

Current through 20Ω is I_0 . Then, $9 + 20 I_0 = 500 I_0 \Rightarrow I_0 = 9/480$ giving $V_{th} = 9 + 20 I_0 + 400 I_0 = 16.875 \text{ V}$.

Next, when a-b is short-circuited, let the current flowing from terminal a to terminal b be I_{sc} . Let the node voltage between the resistors 20Ω and 200Ω be V_x .

Then, $(V_x - 9)/20 + V_x/500 + V_x/200 = 0 \Rightarrow V_x = 7.895 \text{ V}$

$I_{sc} = 2I_0 + V_x/200 = 2V_x/500 + V_x/200 = 0.071 \text{ A}$

Now, $R_{th} = \text{Equivalent resistance across a-b} = V_{th}/I_{sc} = 237.676 \Omega$

Maximum power delivered to the load $R_L = 0.25 V_{th}^2 / R_{th} = 0.3 \text{ W}$ (approx.)

Solution of problem 4:

(i) Assuming the transistor to be in the active region –

$$\begin{aligned}V_{CC} &= R_C(I_C + I_B) + I_B R_B + 0.7 + I_E R_E \\I_B &= \frac{10 - 0.7}{R_C(\beta + 1) + R_B + (\beta + 1)R_E} \\&= \frac{9.3}{101 \cdot 4.7 + 250 + 101 \cdot 1.2} = 0.011 \text{ mA}\end{aligned}$$

$$I_C = 1.1 \text{ mA}$$

$$V_C = 10 - 4.7 \cdot (1.1 + 0.011) = 4.78 \text{ V}$$

$$V_E = 1.2 \cdot 101 \cdot (0.011) = 1.33 \text{ V}$$

$$\text{Therefore } V_{CE} = V_C - V_E = 3.45 \text{ V}$$

Note that $V_B = 2.03 \text{ V}$ implying that the C-B junction is reverse biased as it should be for the transistor to operate in the active region.

(ii) Assuming the transistor to be in the active region –

Thevenin's Equivalent of the Base Voltage supply gives

$$V_{BB} = \frac{10}{3} \text{ V} \quad R_B = R_1 \parallel R_2 = 13.333 \text{ K}\Omega$$

$$V_{BB} = I_B R_B + 0.7 + I_E R_E$$

$$I_B = \frac{3.333 - 0.7}{13.333 + (101)1.2} = 0.0196 \text{ mA}$$

$$I_C = 1.96 \text{ mA}$$

$$V_C = 10 - 2.8 \cdot 1.96 = 4.51 \text{ V}$$

$$V_E = 1.2 \cdot (101) \cdot 0.0196 = 2.38 \text{ V}$$

$$V_B = V_E + 0.7 = 3.08 \text{ V}$$

$$\text{Therefore } V_{CE} = V_C - V_E = 2.13 \text{ V}$$

Note that B-C junction will be reverse biased so transistor is indeed in the active region

Solution of problem 5:

In this case, $V_{BB} = 5 \text{ V}$ and $R_B = 10 \text{ K}\Omega$.

If transistor is assumed to be in the active region, then –

$$I_B = \frac{5 - 0.7}{10 + 101 \cdot 1.2} = 0.0328 \text{ mA} \quad I_C = 3.28 \text{ mA} \quad I_E = 3.313 \text{ mA}$$

$$\text{and } V_E = 3.976 \text{ V} \quad V_B = 4.676 \text{ V} \quad V_C = 0.816 \text{ V}$$

But this would make B-C forward biased which is clearly impossible. Therefore, **transistor cannot be in the active region.**

If transistor is assumed to be in the saturation region, then –

$$\begin{aligned} 5 - 0.7 &= 10I_B + 1.2(I_B + I_C) & 11.2I_B + 1.2I_C &= 4.3 \\ 10 - 0.1 &= 2.8I_C + 1.2(I_B + I_C) & 1.2I_B + 4I_C &= 9.9 \end{aligned}$$

$$\text{Solving, we get} \quad I_B = 0.122 \text{ mA} \quad I_C = 2.44 \text{ mA} \quad I_E = 2.562 \text{ mA}$$

Note that $I_C < \beta I_B$, therefore **the transistor is indeed in saturation**